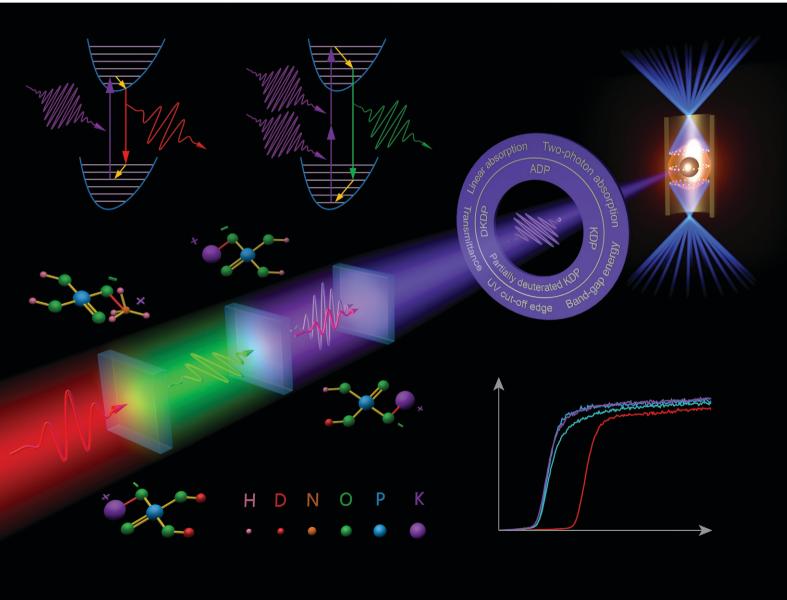
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# Deep-UV optical properties of KDP-family crystals: a comprehensive characterization

Zijian Cui, \* Mingying Sun,\* De'an Liu and Jianqiang Zhu

As a class of widely used optical materials,  $KH_2PO_4$  (KDP)-family crystals play an important role in the generation of infrared, visible, UV, and deep-UV lasers, but their deep-UV optical characteristics have been lacking in systematic research. Aiming at the typical KDP-family nonlinear crystals, including  $NH_4H_2PO_4$ , KDP,  $K(H_{1-x}D_x)_2PO_4$  (partially deuterated KDP), and  $KD_2PO_4$  crystals, we systematically investigated their transmittance, cut-off edge, band-gap energy, linear absorption, and nonlinear two-photon absorption (TPA) properties in the deep-UV spectral region. By using a vacuum-UV spectrophotometer, the UV absolute transmittances were measured in the range of 160–290 nm. Based on the measured results, the UV cut-off edges of these crystals were obtained and band-gap energies were calculated. By using an Nd: YLF picosecond laser (1053 nm, 9 ps, 10 Hz), the fourth and fifth harmonics (263.2 and 210.5 nm) were generated respectively via a  $LiB_3O_5$  crystal and two  $\beta$ -BaB $_2O_4$  crystals. The anisotropic linear absorption and nonlinear TPA coefficients of the above KDP-family crystals were obtained in detail from intensity-dependent transmittance measurements at 263.2 and 210.5 nm with ordinary and extraordinary polarization states. This comprehensive investigation of the deep-UV optical properties of commonly used KDP-family optical materials and the obtained new data can provide an important parameter basis for crystal growth with higher optical purity, deep-UV laser generation, and applications.

#### 1 Introduction

KDP-family crystals represented by NH<sub>4</sub>H<sub>2</sub>PO<sub>4</sub> (ADP), KH<sub>2</sub>PO<sub>4</sub> (KDP), and KD<sub>2</sub>PO<sub>4</sub> (DKDP) are a class of optical materials with a long history and excellent performances, and have been widely used in many important optical functional devices. 1-4 One of the most typical applications is that KDP and DKDP crystals are commonly used as electro-optic switches and modulators to control or modulate laser radiation due to their large electro-optical coefficients.<sup>4,5</sup> In the field of nonlinear optics, because of adequate nonlinear optical coefficients and high laser damage thresholds, 6-12 as shown in Table 1, KDPfamily crystals are the key materials in frequency converters, which can achieve the second-, third-, and fourth-harmonic generation of lasers near 1 µm. 13,14 In addition, KDP-family crystals also have a remarkable feature where their growth sizes exceed that of any other water-soluble crystals, 2,4,15 which makes them indispensable materials for obtaining high-energy and high-power lasers in large laser facilities such as the National Ignition Facility, the LMJ facility, and the ShenGuang facility. 16-18 Owing to a series of significant advantages and improvements in the growth process, the application fields of KDP-family crystals are continuously expanded. Particularly in

Key Laboratory of High Power Laser and Physics, Shanghai Institute of Optics and Fine Mechanics, Chinese Academy of Sciences, Shanghai 201800, China. E-mail: cuizijian@siom.ac.cn, sunmy@siom.ac.cn recent years, the research on temporal compression of high-power laser pulses, Cherenkov radiation, and high-energy deep-UV laser radiation generation based on KDP-family crystals has attracted a lot of attention. <sup>19–23</sup>

The methods of growing KDP-family crystals mainly include the traditional temperature cooling technique and

Table 1 Damage thresholds of KDP crystals at different wavelengths

λ (nm)	Pulse width (ns)	Beam diameter	Damage test	Damage threshold (J cm <sup>-2</sup> )
1064	1.1	30 μm	_	11.7–12.3 (a/b) <sup>11</sup> 19.5–23 (c) <sup>11</sup>
	3	_	_	34 <sup>8</sup>
	3	0.9-1.9 mm	600-on-1	24-34 <sup>9</sup>
	10	1 mm	N-on-1	$64^{7}$
	11	320 μm	1-on-1	49 <sup>10</sup>
532	1	30 μm	_	$6-13.5 (a/b)^{11}$
				$12-20 (c)^{11}$
	3	_	_	$20^{8}$
	11	220 μm	1-on-1	$22^{10}$
			R-on-1	$29^{10}$
355	0.85	30 μm	_	$4.3-4.8 (a/b)^{11}$
				$4.8-5.3 (c)^{11}$
	3	287 μm	_	8.72 <sup>12</sup>
		_ `	_	12 <sup>8</sup>
		0.9-1.9 mm	600-on-1	15-20 <sup>9</sup>
	10	1 mm	N-on-1	$28.6^{7}$
	11	450 μm	1-on-1	$18^{10}$
266	3	_	_	38

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the "point seed" rapid growth technique. 2,12,24-26 The traditional technique is to slowly reduce the solution temperature to obtain the driving force for crystal growth. This technique has the advantages of large pyramidal face growth, high optical homogeneity, and high damage threshold, but its disadvantages are that it requires a large cross-section seed crystal, slow growth speed, and long growth cycles. The rapid growth technique can increase the growth rate of KDP-family crystals by an order of magnitude, and the preparation of a point seed crystal is easy. However, there are two main problems with the rapid growth technique.<sup>26</sup> First, the growth solution needs to maintain high stability, and second, compared with the traditional technique, the optical qualities of the crystals obtained by the rapid growth technique are decreased, such as an increase of internal light scattering and UV absorption, a decrease of optical homogeneity, and a reduction of laser damage threshold. At present, by studying the properties of KDP-family crystals under different growth conditions (including raw materials, growth methods, seed orientation, and deuterium content), the optimal growth process has been determined and large-aperture and high-quality KDPfamily crystals have been successfully obtained by both the traditional method and rapid growth method. 12,27-29 Single crystal optical devices with a size of >400 mm can be fabricated. Meanwhile, a series of Fe3+, Zn2+, and borax additive doped KDP crystals were grown, and the influence of doping on the optical properties of the crystal, such as transmissivity, nonlinear optical properties, laser-induced

generation, was also studied. 30-32 To better apply KDP-family crystals, it is important to accurately obtain material parameters in the deep-UV spectral systematically understand their optical to characteristics. Presently, although the partial deep-UV optical properties of a few crystals in the KDP-family have been reported in some studies, 23,33-42 these results are fragmentary. There is still a lack of systematic data on the material optical properties of KDP-family crystals in the deep-UV waveband near 200 nm, especially the deep- and vacuum-UV transmittance, linear absorption, and nonlinear twophoton absorption (TPA) of the crystals with different deuterium contents. In addition, for deep-UV lasers with different polarization states, it is also crucial to reveal the polarization dependence of the absorption loss in KDP-family crystals for their applications in nonlinear optics. To the best of our knowledge, the measurement of quite a few is still lacking, which cannot provide parameters comprehensive information on the linear absorption coefficient and nonlinear TPA of KDP-family crystals. Therefore, it is necessary to deeply investigate the optical properties of these materials in the deep-UV waveband.

damage threshold, Raman spectrum, and second-harmonic

Here, we systematically characterized the optical properties of commonly used KDP-family nonlinear crystals in the deep-UV spectrum range, including the UV transmittance, cut-off edge, band-gap energy, linear absorption, and nonlinear TPA coefficients. Four uncoated crystal samples of ADP, KDP, 70% deuterated KDP, and DKDP (deuterium content >98%) were prepared (110 cut), and they were all grown using traditional technology. The crystal samples are shown in Fig. 1. In this work, the anisotropic linear absorption and nonlinear TPA coefficients of each crystal sample were measured in detail at two typical deep-UV wavelengths of 263.2 and 210.5 nm, including two polarization states of ordinary and extraordinary light (o light and e light). In addition, for the measurement of the TPA coefficient, we used a CCD camera to measure the transverse profile of the beam instead of the traditional method of assuming the spatial profile distribution of the laser intensity, thereby more accurately reconstructing the threedimensional laser intensity distribution to achieve precise measurement.

# 2 UV transmittance and band-gap energy

By using a vacuum-UV (VUV) spectrophotometer (Metrolux ML6500, Germany, operation pressure:  $<3 \times 10^{-3}$  Pa, wavelength ranges with double lamps: 115 to 230 nm and 160 to 320 nm), we measured the UV absolute transmittances of the KDP-family crystal samples in the spectral region of 160-290 nm (0.2 nm step), as shown in Fig. 2(a). Their UV cut-off wavelengths, which are defined by the "0" transmittance level, are shown in Table 2. Compared with the KDP, 70% deuterated KDP, and DKDP crystals, the ADP crystal has longer UV cut-off edges, which means that it has a smaller band-gap energy  $(E_{\sigma})$ . It can also be seen that the KDP, 70% deuterated KDP, and DKDP crystals have similar UV cut-off wavelengths, while the overall UV transmittances of the 70% deuterated KDP crystal are slightly lower than those of the KDP and DKDP crystals. The main reason is that there may be more impurities in the 70% deuterated KDP crystal than in the KDP and DKDP crystals. For crystals grown in aqueous solutions, such as KDP-family crystals, the presence of growth defects (including intrinsic point defects, scattering particles, and impurity ions) can cause rather strong absorptions in the UV waveband. 40,43-54 Typical intrinsic point defects in KDP-family crystals include H<sub>i</sub>, V<sub>P</sub>,  $V_{\rm K}$ , and  $V_{\rm N}$ . Particularly, the  $V_{\rm P}^{5-}$  defect is regarded as one of the most destructive intrinsic point defects in the KDP crystal, which could introduce a strong defect state in the

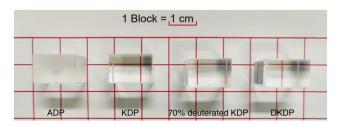


Fig. 1 Photograph of ADP, KDP, 70% deuterated KDP, and DKDP crystal samples.

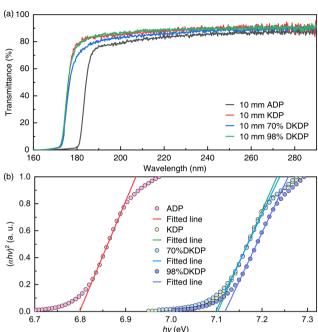


Fig. 2 (a) Experimentally measured absolute transmittance spectra of the ADP, KDP, 70% deuterated KDP, and DKDP crystal samples in the UV spectral region of 160-290 nm. (b) Band-gap energies of the ADP, KDP, 70% deuterated KDP, and DKDP crystal samples were determined from the Tauc plots. The fitted linear parts are used to evaluate the band-gap energy at the x-axis intercept.

band gap of KDP and cause extra optical absorption at 310-620 nm. 49,50 For the scattering particles in KDP-family crystals, they can significantly reduce the optical quality of the crystal, 51,52 and the scattering particles can cause light loss in the whole transmission wavebands of the crystals. During the growth of KDP-family crystals, the metal ions in solution, such as Fe3+ [peak absorption wavelength (PAW) <290 nm], Al<sup>3+</sup> (PAW 266 nm), Cr<sup>3+</sup> (PAW 358 & 270 nm), and Pb<sup>2+</sup> (PAW <230 nm), can significantly enhance the absorption of the UV waveband, and the absorption is closely related to the concentration of metallic absorption impurities. 53-56 The higher the concentration, the lower the UV transmittance. Hence, for the KDP crystal, especially the one obtained by the rapid growth method, its prismatic part has higher UV absorption than the pyramidal part because of the charge states of the (100) and (101) planes, and trivalent metals (including Al<sup>3+</sup>, Fe<sup>3+</sup>, Cr<sup>3+</sup>) are mostly incorporated in the prismatic sector.<sup>56</sup> In addition, the absorption loss is also closely related to the orientation (or polarization), and the results show that at the same ion concentration, the absorption along the z-direction is always greater than that along the type-II phase-matching direction. 30,57

In Table 2, the measured UV cut-off edges were slightly different from the results reported in the literature. The first reason is that the thicknesses of the crystal samples are different. 33,34 What's more, as mentioned above, for KDP-family crystals, metal ion impurities have a significant effect on UV transmittance. Therefore, the crystal samples grown by different processes in the literature will lead to diverse measured results.

Since the band-gap of a material describes the energy required to excite an electron from the valence band to the conduction band and can be used to predict the photophysical and photochemical properties of materials, accurate determination of the band-gap energy is very important. In 1966, Tauc proposed a method to estimate the band-gap energy by using optical absorption spectra, and after further development, it has become a common method to calculate the band-gap energy.<sup>58</sup>

The Tauc method shows that the energy-dependent absorption coefficient  $\alpha$  can be expressed by the following equation:

$$(ahv)^{1/n} = A(hv - E_g)$$
 (1)

where h is the Planck constant, v is the photon frequency, Ais a proportionality constant,  $E_g$  is the band-gap energy, and the factor n depends on the nature of the electron transition and is equal to 1/2 or 2 for direct and indirect transition, respectively.

Based on the measured results of the UV transmittance, we calculated the band-gap energies of the ADP, KDP, 70% deuterated KDP, and DKDP crystals using the Tauc method. The results are shown in Fig. 2(b) and Table 2. The measured UV cut-off edges and band-gap energies revealed an almost perfect agreement with the reported data. It is worth noting that for the DKDP crystals with different deuterium contents, their UV cut-off edges and band-gap energies are almost identical. Therefore, it can be reasonably concluded that the deuterium content almost does not affect these properties.

# 3 Measurement of linear absorption and nonlinear TPA coefficients

#### 3.1 Experimental setup

To measure the linear absorption and nonlinear TPA coefficients, an Nd:YLF laser (1053 nm, 10 Hz) with a pulse

Table 2 Experimentally measured UV cut-off edges and calculated band-gap energies of the crystal samples

	UV cut-off edge		Band-gap energy $E_{ m g}$	
Crystal	Experiment	Literature	Experiment	Literature
ADP	180.2 nm	181 nm <sup>33</sup>	6.80 eV	6.81 eV <sup>35</sup>
KDP	171.6 nm	174 nm <sup>33</sup>	7.10 eV	6.95, 7.2 eV <sup>35,36</sup>
70% DKDP	171.8 nm	_	7.10 eV	_
DKDP	171.4 nm	<200 nm <sup>34</sup>	7.12 eV	7.1–7.2 eV <sup>37</sup>

duration of ~9 ps (FWHM) and maximum output energy of 45 mJ was used as the fundamental laser source ( $\omega_1$ ). The transverse profile is a circular spot with a diameter of 4.3 mm defined as the measurement of 10% of the peak irradiance point. To generate a deep-UV laser of 263.2 and 210.5 nm, a 4.5 mm-thick LiB<sub>3</sub>O<sub>5</sub> (LBO) crystal ( $\theta = 90^{\circ}$ ,  $\varphi =$ 11°, type-I phase matching) was used to generate the second harmonic ( $ω_2$ ), then a β-BaB<sub>3</sub>O<sub>4</sub> (β-BBO) crystal (θ = 48.4°, φ = 0°, type-I phase matching) with a thickness of 1.2 mm was used to generate the fourth harmonic  $(\omega_4)$ , and finally, a β-BBO crystal (θ = 52.1°, φ = 0°, type-I phase matching) with a thickness of 0.8 mm was used to generate the fifth harmonic  $(\omega_5)$ . The surfaces of each crystal were coated with antireflection films at the corresponding wavelengths.

A schematic diagram of the experimental setup is shown in Fig. 3(a). The temperature of the LBO crystal was always controlled at 55 °C, and the two  $\beta$ -BBO crystals were at room temperature. To obtain laser pulses with high spectral purity, both the generated fourth and fifth harmonics were separated from other wavelength lasers using two dichroic mirrors. The whole experiment involved four laser radiations with different wavelengths, which were 1053, 526.5, 263.2, and 210.5 nm, respectively. The pulse durations of the generated fourth and fifth harmonics were measured using TPA pump-probe experiments, and the measured results are 6.72 and 5.08 ps (FWHM), respectively, as shown in Fig. 3(b) and (c).

The polarization direction of the fundamental wave output from the laser was perpendicular to the horizontal plane, and the polarization directions of the obtained fourth and fifth harmonics were perpendicular and parallel to the horizontal plane, respectively. Due to the strict limitation of the phase matching, the laser radiations obtained by frequency conversion have a good polarization degree, and the polarizations of the fourth and fifth harmonics measured with a Gran prism were better than 150:1.

In the measurement of absorption coefficients, two wedged beam splitters (WBSs, wedge angle: 5 degrees) were used to sample the deep-UV laser energy. Since the MgF2 crystal has a high transmittance and a very weak TPA effect in the deep-UV spectral region,<sup>59</sup> MgF<sub>2</sub> was employed for the material of the WBSs. In addition, to minimize the influence of sampling materials on the results in the measurement process, the reflection scheme of the back surface was adopted to characterize the incident laser energy before the sample, while the laser energy output from the sample was measured by the reflection scheme of the front surface. For the measurement of laser energy, two energy meters (PE9-ES-C, OPHIR, Israel) with the same model were used and calibrated with each other. To reduce the impact of energy fluctuation on the measurement results, 30 pulse energies were measured and averaged each time in the follow-up experiments.

To ensure the accuracy of the measurement results, we firstly calibrated the sampling rates of WBS-1 and WBS-2 at

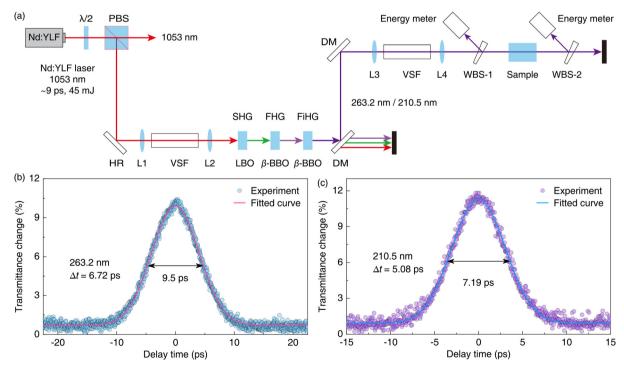


Fig. 3 (a) Experimental setup for measuring the linear absorption and nonlinear TPA coefficients. λ/2, half-wave plate; PBS, polarization beam splitter; HR, high reflector; DM, dichroic mirrors; L1 (f = 300 mm), L2 (f = 400 mm), L3 (f = 400 mm), and L4 (f = 300 mm), lens (deep-UV fused silica); VSF, vacuum spatial filter; WBS, wedged beam splitter. Measured results of the (b) fourth and (c) fifth harmonic pulse durations measured by TPA pump-probe experiments. A Gaussian temporal profile is assumed for the fit, and a deconvolution factor of 1.414 is used to extract the FWHM pulse duration.

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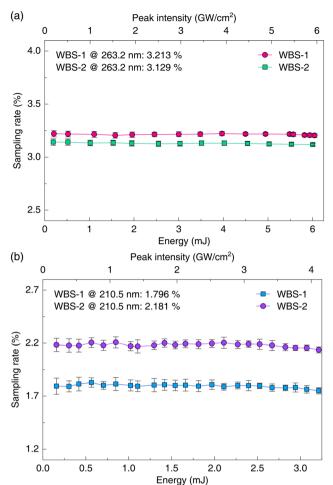


Fig. 4 Sampling rates of (a) WBS-1 and (b) WBS-2 at different incident energies at the wavelengths of 263.2 and 210.5 nm.

different incident energies, and the results are shown in Fig. 4. It can be seen from the measured results that there is little change in the sampling rate of the WBSs at different laser energies, which means that each sampling rate can be regarded as a constant in this experiment. At the wavelengths of 263.2 and 210.5 nm, the sampling rates of WBS-1 are 3.213% and 1.796%, respectively, and those of WBS-2 are 3.129% and 2.181%, respectively. The fluctuations of the fourth and fifth harmonic energy sampling rate were less than 0.05% and 2%, respectively, and they were mainly caused by the fluctuation of laser energy during the measurement process and the measurement deviation of the energy meter at different wavelengths and energy levels.

#### 3.2 Linear absorption coefficients

For the deep-UV laser, numerous optical materials show a strong nonlinear TPA effect in a high-peak-power regime. Therefore, the measurement of the linear absorption coefficients of materials in the deep-UV region needs to use a laser with low peak power to ensure that the nonlinear absorption is far weaker than the linear absorption. In this part of the experiment, the peak intensities of the incident lasers (both 263.2 and 210.5 nm) were controlled below 100 MW cm<sup>-2</sup>. For the beam normally incident to the crystal sample, the surface reflection R, linear transmittance  $T_L$ , and linear absorption coefficient of the crystal sample can be described as:40,60

$$R = \left(\frac{n-1}{n+1}\right)^2 \tag{2}$$

$$T_{\rm L} = \frac{(1 - R)^2}{1 - R^2 e^{-2\alpha L}} e^{-\alpha L}$$
 (3)

$$\alpha = -\frac{1}{L} \ln \left[ \frac{-(1-R)^2 + \sqrt{(1-R)^4 + 4T_L^2 R^2}}{2T_L R^2} \right]$$
(4)

where n is the refractive index of o light or e light,  $\alpha$  is the linear absorption coefficient, and L is the length of the crystal sample. The specific parameters of the prepared crystal samples, including length, cutting angles, and refractive indices used in the subsequent calculation are shown in Table 3.34,61,62

As the laser intensity gradually increases from zero, the lowintensity transmittances of o light and e light in the ADP, KDP, 70% deuterated KDP, and DKDP crystal samples were measured in detail, and the results are shown in Fig. 5. For the whole transmittances of the ADP, KDP, 70% deuterated KDP, and DKDP crystal samples at 263.2 nm, it can be seen that the measured transmittances have good consistency, which indicates that the nonlinear absorption effect is very weak in this measurement process. However, at the wavelength of 210.5 nm, the transmittances decrease slightly with the increase of energy, especially when the peak intensity is greater than 10 MW cm<sup>-2</sup>. This means that the nonlinear absorption effect has

Table 3 Parameters of the crystal samples and the corresponding refractive indices at 263.2 and 210.5 nm

Crystal	Length	Orientation	Polarization	n @ 263.2 nm	n @ 210.5 nm
ADP	10 mm	$\theta = 90^{\circ}, \ \phi = 45^{\circ}$	0	1.5813264	1.6314394
		, ,	e	1.5275895	1.5715802
KDP	10 mm	$\theta$ = 90°, $\phi$ = 45°	О	1.5609935	1.6061728
		,,	e	1.5113071	1.5499245
70% DKDP	10 mm	$\theta$ = 90°, $\phi$ = 45°	О	1.5570717	1.6055643
			e	1.5091906	1.5472657
DKDP	10 mm	$\theta$ = 90°, $\phi$ = 45°	О	1.5555002	1.6053208
			e	1.5083431	1.5462008

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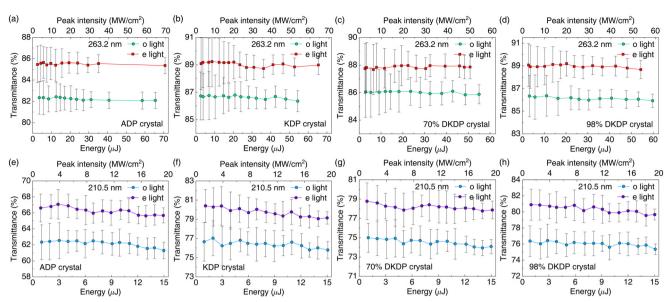


Fig. 5 Low-intensity transmittances of ADP, KDP, 70% deuterated KDP, and DKDP crystal samples at (a)-(d) 263.2 and (e)-(h) 210.5 nm.

begun to appear. Therefore, the measured data with a peak intensity of less than 10 MW cm<sup>-2</sup> were used to calculate the linear absorption coefficients. According samples, parameters the crystal low-intensity transmittances, and eqn (2)-(4), the linear absorption coefficients of the crystal samples were obtained from numerical calculations, and the results are listed in Table 4.

Since the employed laser has high stability and the linear absorption coefficient is only determined by the laser energy and independent of the peak power, the measurement error mainly arises from the energy measurement and the calculation of surface reflection loss. According to the deviation of the energy detector (2-5%) and the accuracy (<1%) of the refractive index, the measurement error is estimated to be less than 6%. In Table 4, we also listed the reported data of the linear absorption coefficient as far as possible. Compared with them, it can be seen that the results measured in this work are in good agreement with some published data, but there are also obvious differences with several data. An important reason is that the materials used by different research groups to characterize UV optical properties, their growth processes, and the experimental conditions are different. A number of fragmentary reported

results make it difficult to form a complete and unified conclusion.

#### 3.3 Nonlinear TPA coefficients

For the determination of the TPA coefficient, accurately measuring the intensity-dependent energy transmittance and reconstructing the three-dimensional distribution of laser intensity are two critical procedures. To measure the energy transmittances at different intensities, a high-intensity and intensity-tunable laser source is required. Generally, the output energy of the laser can be changed by adjusting the delay between the signal light and the xenon lamp or laser diode pump. However, the transverse distribution of the output beam will also be changed obviously in this way, which is unfavorable to the reconstruction of the laser intensity distribution, thus affecting the accuracy of TPA coefficient results. Therefore, the output energy from the Nd: YLF laser was set to 15 mJ during the whole measurement process, and the energy tuning was controlled via the halfwave plate and polarization beam splitter to ensure that the pulse duration, temporal waveform, and spatial distribution of the output laser have a good consistency.

Table 4 Experimentally measured linear absorption coefficients of the crystal samples at 263.2 and 210.5 nm

Crystal	Polarization	$\alpha$ (a) 263.2 nm (cm <sup>-1</sup> )		$\alpha$ @ 210.5 nm (cm <sup>-1</sup> )	
		Experiment	Literature	Experiment	Literature
ADP	0	0.0916	_	0.357	
	e	0.0674	$0.07, 0.035^{34,38,39}$	0.310	_
KDP	0	0.0452	_ ^	0.158	$0.2,  0.31^{34,40}$
	e	0.0314	$0.01-0.2,0.03,0.27^{34,40}$	0.131	,
70% DKDP	O	0.0535	$0.0839^{41}$	0.183	_
	e	0.0454	$0.0671^{41}$	0.152	_
DKDP	0	0.0525	_	0.163	_
	e	0.0330	$0.035^{38,39}$	0.125	_

To reconstruct the laser intensity distribution, a common method is to use an approximate function to establish a mathematical description based on the measurement results of the laser beam. Essentially, this is only an approximation, especially the description of the spatial profile. This is not the best way to determine the TPA coefficient because it is extremely dependent on the intensity distribution. In fact, based on the high stability laser, it is a more straightforward and practical method that directly uses the measured data of the beam spatial profile to reconstruct the complete three-dimensional intensity information of the laser. Therefore, the transverse profile measured using a CCD camera was used here instead of the traditional method to reconstruct the laser intensity distribution more accurately and truly.

Experimentally, the spatial profiles of the fourth and fifth harmonics were measured. The number of effective pixels and the pixel spacing of the CCD camera are 1928  $\times$  1448 and 3.69  $\mu m$ , respectively. 20 sets of spatial profile data were measured both at 263.2 and 210.5 nm, and they were normalized by dividing by the respective maximum values. The normalized intensity distributions are numerically integrated, and the integration results are shown in Fig. 6(a) and (b). According to the integration values, it can be seen that the transverse distributions of the beams at the two wavelengths have a good consistency. The final intensity distributions of the 263.2 and 210.5 nm lasers are shown in Fig. 6(c) and (d), and they were used to reconstruct the three-dimensional intensity distribution and calculate the TPA coefficient.

Based on the measured temporal and transverse spatial distribution of the pulse, a normalized intensity distribution of laser radiation was established, and the true 3D intensity distribution of the beam can thus be reconstructed according to the measured energy. Considering both linear absorption and nonlinear TPA absorption, for the laser pulse propagating along the z direction, the change of intensity I with propagation can be expressed as: $^{40,63}$ 

$$\frac{\mathrm{d}I}{\mathrm{d}z} = -\alpha I - \beta I^2 \tag{5}$$

where  $\beta$  is the TPA coefficient.

For a beam with a temporal Gaussian intensity profile, its three-dimensional intensity distribution  $I_{\rm in}(x, y, t)$  and the intensity-dependent transmittance  $T_{\rm NL}$  through the crystal sample can be described as:

$$I_{\text{in}}(x, y, t) = I(x, y) \exp\left(-4 \ln 2 \frac{t^2}{\tau^2}\right)$$
 (6)

$$T_{\rm NL} = \frac{\int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} I_{\rm out}(\beta, x, y, t) dx dy dt}{\int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} \int_{-\infty}^{\infty} I_{\rm in}(x, y, t) dx dy dt}$$
(7)

where  $I_{\rm in}(x, y, t)$  and  $I_{\rm out}(\beta, x, y, t)$  are the three-dimensional (spatial and temporal) intensity distributions of the incident and output beams, respectively;  $\tau$  is the pulse duration defined by the FWHM.

The maximum energy of the second harmonic generated by using an LBO crystal was 11.1 mJ, and the corresponding conversion efficiency is 74%. Subsequently,  $\beta$ -BBO crystals were used to generate the fourth and fifth harmonics with maximum energies of 6.3 and 4.2 mJ, respectively, and the conversion efficiency was 42% and 28%, respectively. The

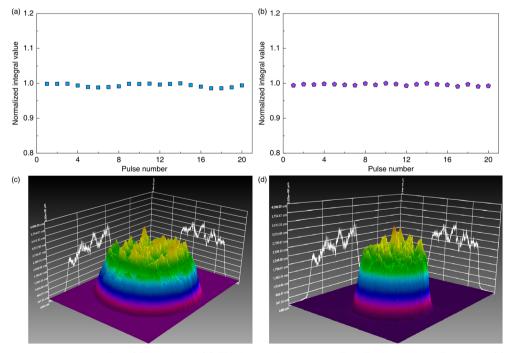


Fig. 6 Numerical integrations of normalized (a) fourth and (b) fifth harmonic spatial profiles. Final spatial profiles of the (c) fourth and (d) fifth harmonics used for the TPA coefficient calculation.



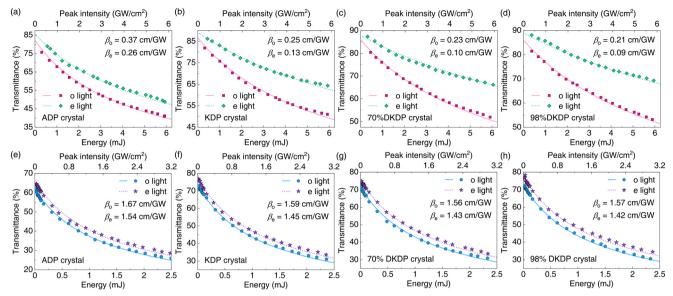


Fig. 7 Intensity-dependent transmittances of ADP, KDP, 70% deuterated KDP, and DKDP crystal samples at (a)-(d) 263.2 and (e)-(h) 210.5 nm. The symbols denote the experimental results, and the solid and dashed lines denote the best-fitted results by varying the value of the TPA coefficients.

accessible ranges of intensities at 263.2 and 210.5 nm in the collimated beam were up to 6.2 and 5.3 GW cm<sup>-2</sup>, respectively. The measured intensity-dependent transmittances of the ADP, KDP, 70% deuterated KDP, and DKDP crystal samples at 263.2 and 210.5 nm are shown in Fig. 7. According to eqn (6) and (7), we numerically fitted the experimental data by varying the value of the TPA coefficient, and the final results are listed in Table 5. In this experiment, the errors of the pulse duration determination (350-500 fs) and energy calibration (2-5%) were the main factors that contributed to the absolute error (<15%) in the TPA coefficient determination. Deep-UV laser sources have key applications in numerous fields including laser physics, plasma experiments, and industrial processing, and TPA is an important loss mechanism that affects the generation and propagation of high-intensity deep-UV laser radiation. However, as the key materials to obtain deep-UV laser sources, reports on the TPA coefficients of KDP-family crystals are fragmentary presently. Hence, the TPA coefficients systematically presented in Table 5 have great practical significance for understanding the generation, propagation, loss characteristics, and applications of deep-UV lasers in KDP-family materials.

#### 3.4 Discussion

Based on the results of the above optical characterization, it can be found that the KDP-family crystals are a class of optical materials with excellent performances in the deep-UV band, which makes them have important application potential in the generation of deep-UV laser sources. Especially the KDP and deuterated KDP crystals, compared with the ADP crystal, they not only have higher transmittance, shorter UV cut-off edge, and larger band-gap energy but also have weaker linear absorption and nonlinear TPA effects, which means that they have lower energy loss. And it can be further seen that the linear and nonlinear absorption effects at the wavelength of 210.5 nm are more obvious than those at 263.2 nm because the photon energy is higher and closer to the UV cut-off edge of the crystal. In addition, the measured results show that the e-light loss in the KDP-family crystals is generally lower than that of o light in the deep-UV region, whether linear absorption or nonlinear absorption. The results presented in the UV waveband are similar to those reported in the literature in the visible waveband.30,57 And, for the KDP crystals with

Table 5 Experimentally measured nonlinear TPA coefficients of the crystal samples at 263.2 and 210.5 nm

Crystal	Polarization	$\beta$ (a) 263.2 nm (cm/GW)		$\beta$ @ 210.5 nm (cm/GW)	
		Experiment	Literature	Experiment	Literature
ADP	0	0.37	$0.25,  0.24,  0.11,  0.06^{23,35,38,39}$	1.67	1.2 <sup>23</sup>
	e	0.26		1.54	
KDP	0	0.25	$0.27,  0.26^{35,40}$	1.59	$1.36, 0.6^{40,42}$
	e	0.13		1.45	
70% DKDP	0	0.23	$0.32^{41}$	1.56	_
	e	0.10	$0.17^{41}$	1.43	_
DKDP	0	0.21	$0.027,0.02^{38,39}$	1.57	_
	e	0.09		1.42	_

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different deuterium contents, there is no significant difference in these UV optical characteristics, which indicates that the deuterium content does not significantly enhance or weaken these properties. These parameters fully show that large-aperture KDP-family crystals are especially suitable for obtaining high-energy deep-UV lasers.

#### 4 Conclusion

We have systematically investigated the deep-UV absolute transmittances, cut-off edges, band-gap energies, linear absorption, and nonlinear TPA coefficients of a series of commonly used KDP-family crystals, including ADP, KDP, 70% deuterated KDP, and DKDP. Especially at the typical deep-UV wavelengths of 263.2 and 210.5 nm, the anisotropic linear and nonlinear absorption coefficients of the materials in the case of different polarization states were measured comprehensively. The results show that the KDP-family crystals have short UV cut-off edges, especially the KDP and deuterated KDP crystals, and their UV cut-off edges are close to 170 nm. In terms of absorption losses, both the linear absorption coefficients (0.0674-0.0916 cm<sup>-1</sup> (a) 263.2 nm and 0.31-0.357 cm<sup>-1</sup> (a) 210.5 nm) and TPA coefficients (0.26-0.37 cm/GW @ 263.2 nm and 1.54-1.67 cm/GW @ 210.5 nm) of the ADP crystal are higher than those of KDP and deuterated KDP crystals (0.0314-0.0535 cm<sup>-1</sup> @ 263.2 nm, 0.125-0.183 cm<sup>-1</sup> @ 210.5 nm, 0.09-0.25 cm/GW @ 263.2 nm, and 1.42-1.59 cm/GW @ 210.5 nm). For the KDP crystals with different deuterium contents, their UV cut-off edges, band-gap energies, and absorption coefficients are not significantly different. Since the KDP-family crystals have unparalleled large-scale growth characteristics of other water-soluble crystals, and the refractive index can be controlled by doping deuterium, these unique advantages endow the KDP-family crystals with broad application prospects in the fields of high-energy deep-UV laser generation, deep-UV optical devices, plasma experiments, and advanced scientific instruments. The obtained new optical data and conclusions in this work can provide key technical references for the growth and application in the deep-UV waveband of KDPfamily crystals.

#### Author contributions

Zijian Cui: conceptualization, methodology, investigation, and writing - original draft; Mingying Sun: investigation, validation, and resources; De'an Liu: project administration and writing - review & editing; Jianqiang Zhu: supervision and writing - review & editing. All authors have approved the final version of the manuscript.

#### Conflicts of interest

The authors declare no conflicts of interest.

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